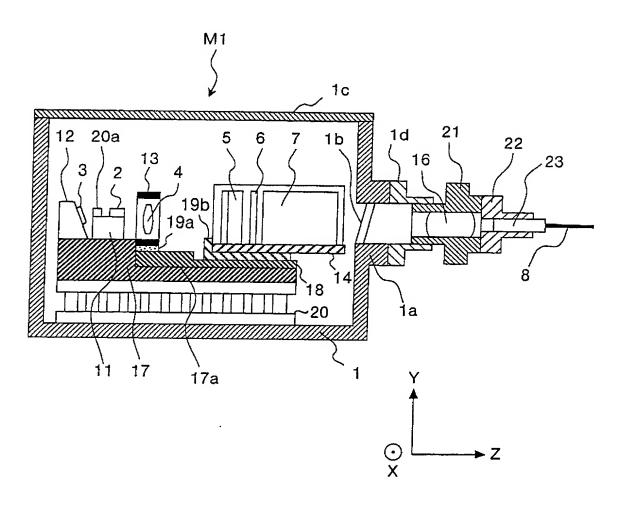
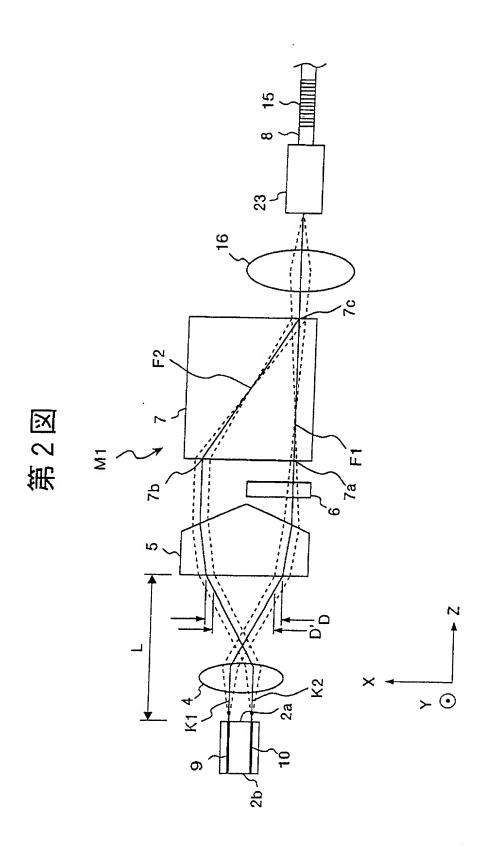
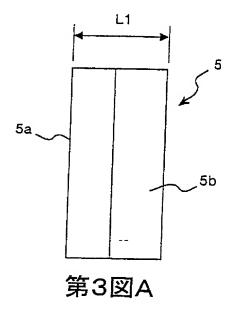
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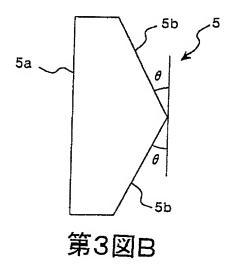


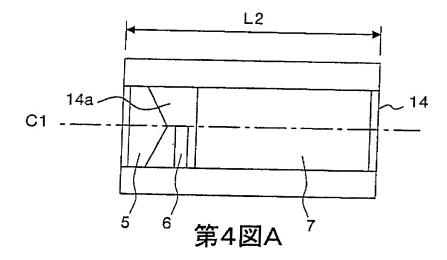
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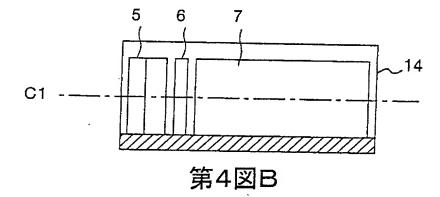


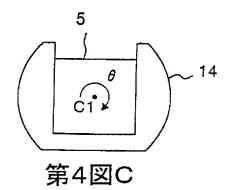


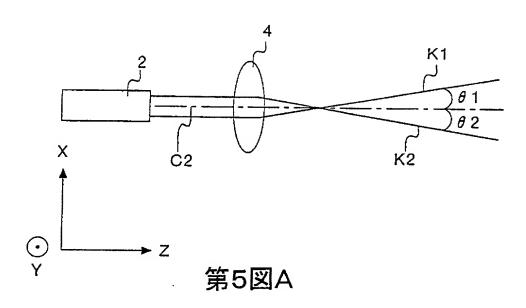


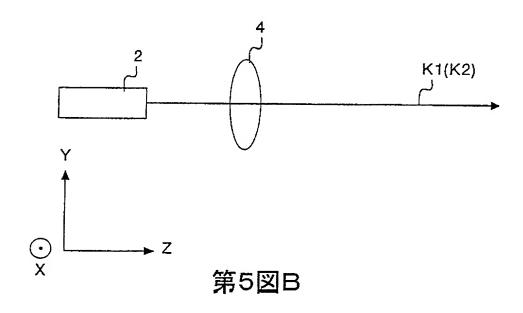


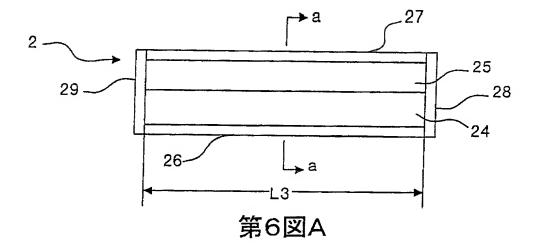


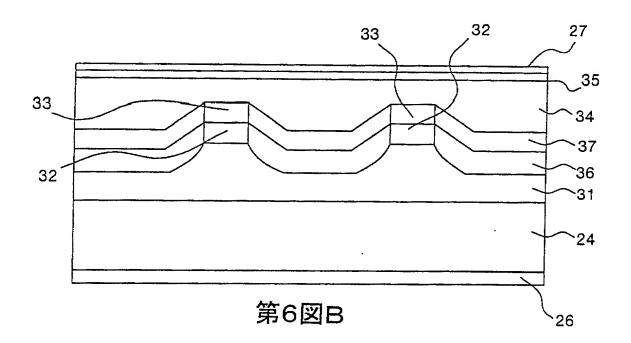




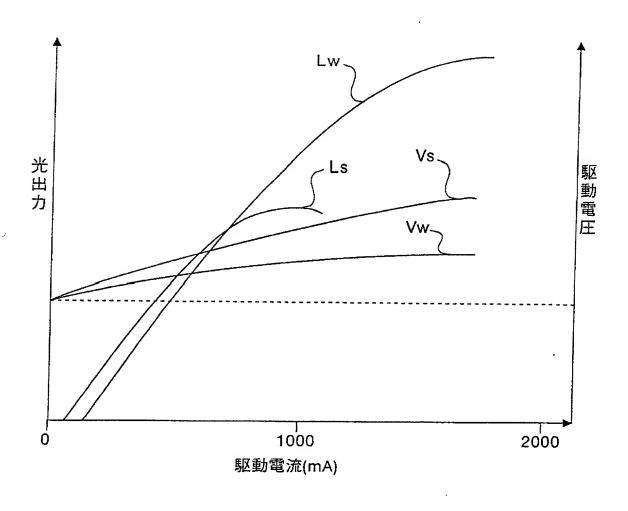




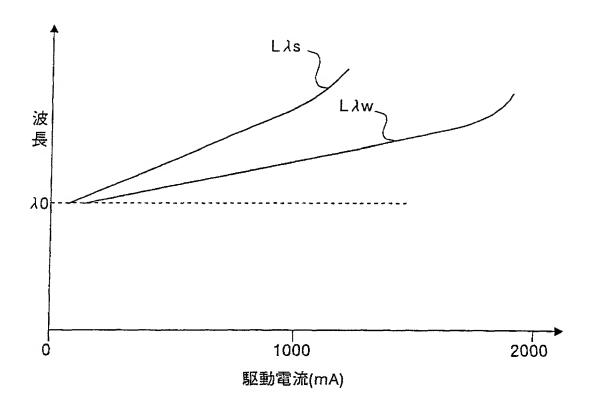


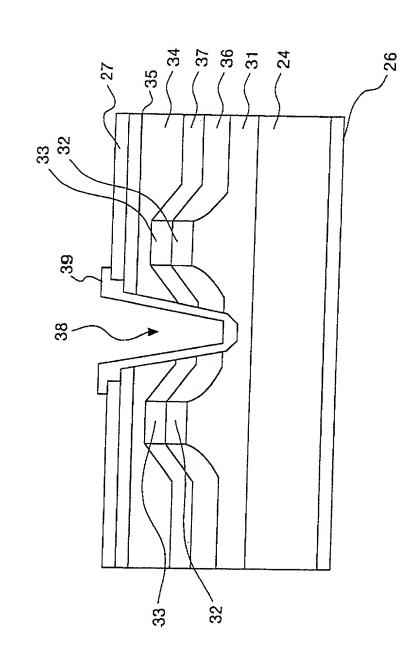


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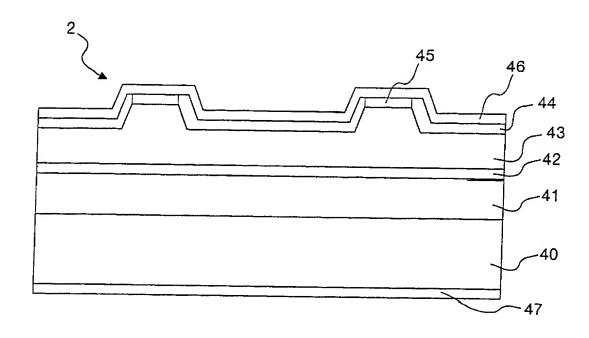
第8図





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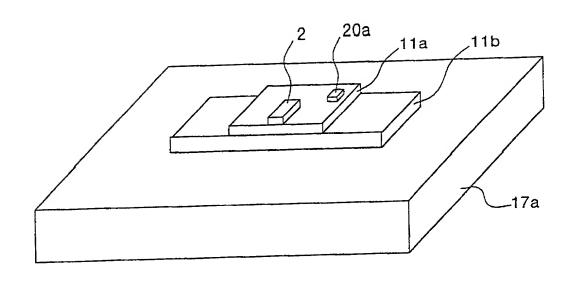
第10図



OBLON, SPIVAK, ET AL DOCKET #: 217494US8 INV: Sadayoshi KANEMARU, et al. SHEET _11_ OF_18_

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第11図



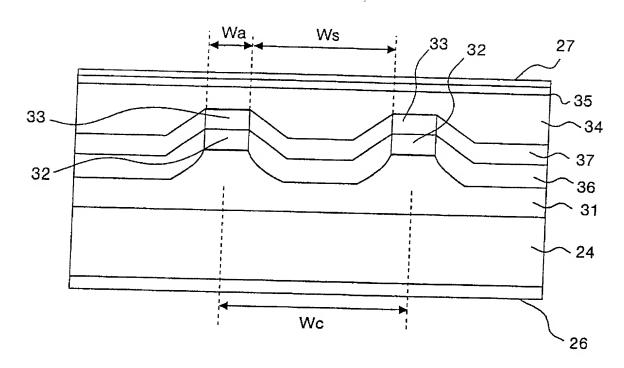
第12図

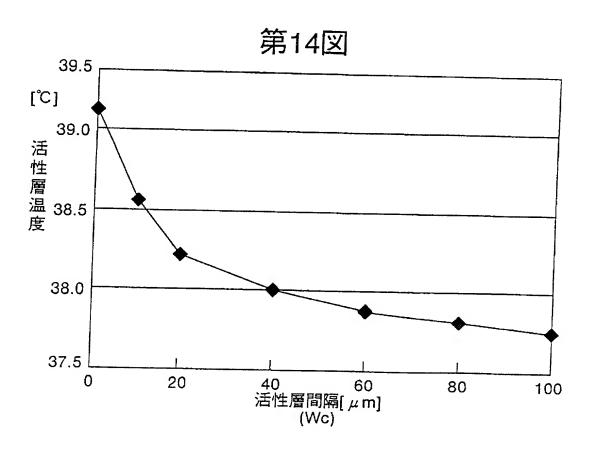
	A	В
- トシンク	CVDダイヤモンド	AIN
	AIN	AIN
	2.5	2.5
交執.暑[\\/]	2.5	2.5
	37.96	49.53
温度[℃] 右活性層	37.96	49.53
	26.76	26.77
	- トシンク - トシンク 左活性層 右活性層 左活性層 右活性層 った活性層	-トシンクCVDダイヤモンド-トシンクAIN左活性層2.5右活性層37.96右活性層37.96

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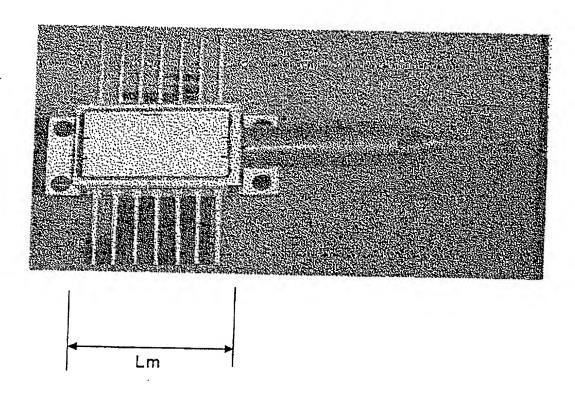
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第13図

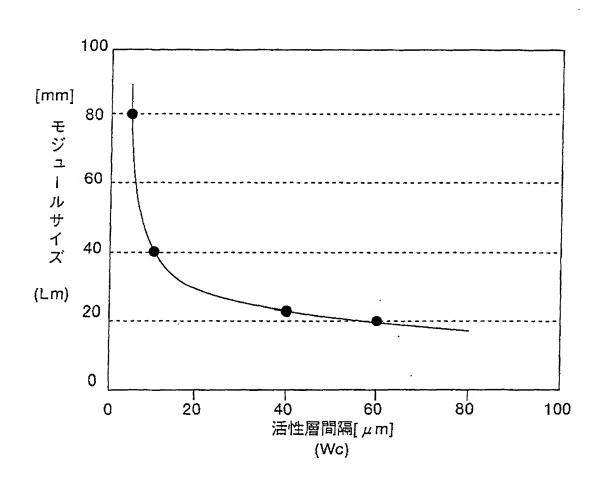




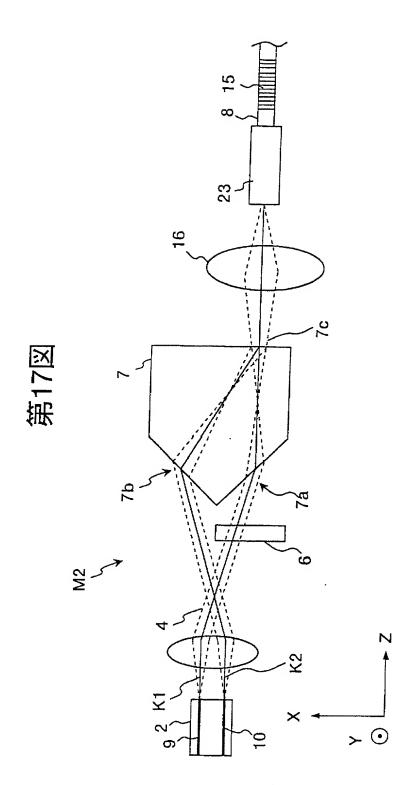
第15図



第16図

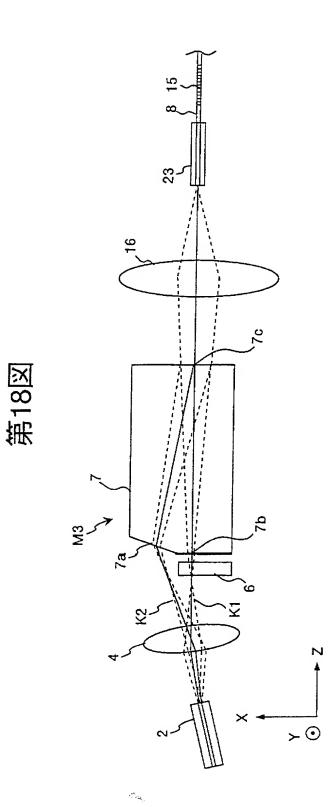


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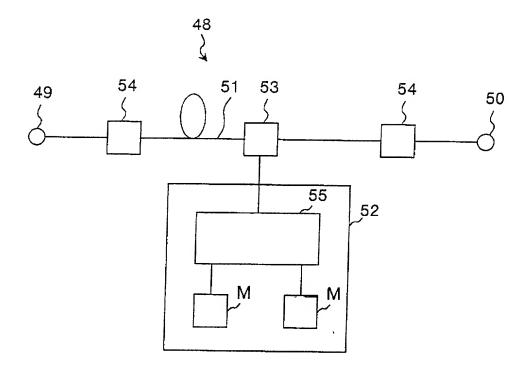


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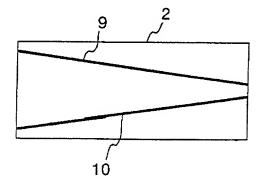




第19図



第20図





第21図

